



NTP8G202NG Information



For Reference Only

Part Number NTP8G202NG
Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 600V 9A TO220

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









NTP8G202NG Specifications

Manufacturer Part Number	NTP8G202NG
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	9A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	8V
Vgs(th) (Max) @ Id	2.6V @ 500μA
Gate Charge (Qg) (Max) @ Vgs	9.3nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	760pF @ 400V
Vgs (Max)	±18V
FET Feature	-
Power Dissipation (Max)	65W (Tc)
Rds On (Max) @ Id, Vgs	350 mOhm @ 5.5A, 8V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220-3
Package / Case	TO-220-3
	Report errors?

NTP8G202NG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NTP8G202NG Payment Methods

































If you have any question about NTP8G202NG, please do not hesitate to contact us!

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